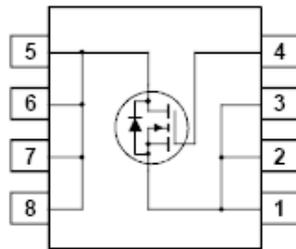
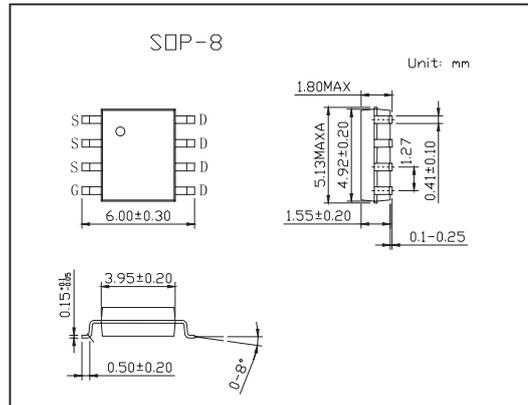


# KDS4470

## ■ Features

- 12.5 A, 40 V.  $R_{DS(ON)} = 9m\Omega @ V_{GS} = 10\text{ V}$
- Low gate charge (45 nC typical)
- High performance trench technology for extremely low  $R_{DS(ON)}$
- High power and current handling capability



## ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Drain to Source Voltage	$V_{DS}$	40	V
Gate to Source Voltage	$V_{GS}$	+30/-20	V
Drain Current Continuous (Note 1a)	$I_D$	12.5	A
Drain Current Pulsed		50	A
Power dissipation (Note 1a)	$P_D$	2.5	W
Power dissipation (Note 1b)		1.4	
Power dissipation (Note 1c)		1.2	
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to 175	$^\circ\text{C}$
Thermal Resistance Junction to Ambient (Note 1a)	$R_{\theta JA}$	50	$^\circ\text{C/W}$
Thermal Resistance Junction to Ambient (Note 1c)	$R_{\theta JA}$	125	$^\circ\text{C/W}$
Thermal Resistance Junction to Case (Note 1)	$R_{\theta JC}$	25	$^\circ\text{C/W}$

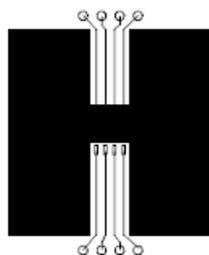
# KDS4470

■ Electrical Characteristics Ta = 25°C

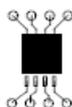
Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Drain-Source Avalanche Energy	EAS	Single Pulse, V <sub>DD</sub> =40V, I <sub>D</sub> =12.5A( Not 2)			370	mJ
Drain-Source Avalanche Current	I <sub>AS</sub>	( Not 2)			12.5	A
Drain-Source Breakdown Voltage	B <sub>V</sub> DSS	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μ A	40			V
Breakdown Voltage Temperature Coefficient	$\frac{\Delta B_{V_{DSS}}}{\Delta T_J}$	I <sub>D</sub> = 250 μ A, Referenced to 25°C		42		mV/°C
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 32 V, V <sub>GS</sub> = 0 V			1	μ A
Gate-Body Leakage, Forward	I <sub>GSSF</sub>	V <sub>GS</sub> = 30 V, V <sub>DS</sub> = 0 V			100	nA
Gate-Body Leakage, Reverse	I <sub>GSSR</sub>	V <sub>GS</sub> = -20 V, V <sub>DS</sub> = 0 V			-100	nA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μ A	2	3.9	5	V
Gate Threshold Voltage Temperature Coefficient	$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	I <sub>D</sub> = 250 μ A, Referenced to 25°C		-8		mV/°C
Static Drain-Source On-Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 12.5 A		6	9	m Ω
		V <sub>GS</sub> = 10 V, I <sub>D</sub> =12.5 A, T <sub>J</sub> = 125°C		9	14	
On-State Drain Current	I <sub>D(on)</sub>	V <sub>GS</sub> = 10 V, V <sub>DS</sub> = 5 V	25			A
Forward Transconductance	g <sub>FS</sub>	V <sub>DS</sub> = 10V, I <sub>D</sub> = 12.5 A		45		S
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V, f = 1.0 MHz		2659		pF
Output Capacitance	C <sub>oss</sub>			605		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			298		pF
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 20 V, I <sub>D</sub> = 1 A, V <sub>GS</sub> = 10 V, R <sub>GEN</sub> = 6 Ω (Note 2)		14	25	ns
Turn-On Rise Time	t <sub>r</sub>			12	22	ns
Turn-Off Delay Time	t <sub>d(off)</sub>			37	59	ns
Turn-Off Fall Time	t <sub>f</sub>			29	46	ns
Total Gate Charge	Q <sub>g</sub>		V <sub>DS</sub> = 20 V, I <sub>D</sub> = 12.5 A, V <sub>GS</sub> = 10 V (Note 2)		45	63
Gate-Source Charge	Q <sub>gs</sub>			27		nC
Gate-Drain Charge	Q <sub>gd</sub>			5		nC
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>				2.1	A
Drain-Source Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 2.1 A (Not 2)		0.7	1.2	V
Diode Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 12.5 A, di <sub>F</sub> /dt = 100 A/ μ s		33		nS
Diode Reverse Recovery Charge	Q <sub>rr</sub>			39		nC

Notes:

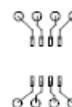
1. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>θJC</sub> is guaranteed by design while R<sub>θCA</sub> is determined by the user's board design.



a) 60°C/W when mounted on a 1in<sup>2</sup> pad of 2 oz copper



b) 106°C/W when mounted on a .04 in<sup>2</sup> pad of 2 oz copper



c) 125°C/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300μs, Duty Cycle < 2.0%